

INFORMATION DISCLOSURE STATEMENT BY APPLICANT		Application No.	10/683,727
		Filing Date	October 10, 2003
		First Named Inventor	Sherman
		Art Unit	1762
(Multiple sheets used when necessary)		Examiner	Eric B. Fuller
SHEET 1 OF 1		Attorney Docket No.	ASMMC.9CP1DV1C1

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U.S. PATENT DOCUMENTS					
Examiner Initials	Cite No.	Document Number Number - Kind Code (if known) Example: 1,234,567 B1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear

FOREIGN PATENT DOCUMENTS					
Examiner Initials	Cite No.	Foreign Patent Document Country Code-Number-Kind Code Example: JP 1234567 A1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear

NON PATENT LITERATURE DOCUMENTS					
Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			T ¹
KMS		MÖLSÄ et al., "Deposition of Cerium Dioxide Thin Films on Silicon Substrates by Atomic Layer Epitaxy," Mat. Res. Soc. Symp., Vol. 325, 1994 Materials Research Society, pp. 341-350			

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Examiner Signature	/Kelly Stouffer/	Date Considered	02/28/2007
*Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			

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